

Invited paper

# Miniaturization of Planar Microwave Devices by Means of Complementary Spiral Resonators (CSRs): Design of Quadrature Phase Shifters

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**Abstract.** In this work, two compact quadrature phase shifters based on metamaterial transmission lines implemented by means of complementary spiral resonators (CSRs) have been designed, fabricated and measured. The structures consist on Y-junctions with output lines exhibiting 90° phase balance. The reported metamaterial-based devices present a size reduction of 64% and 77% as compared to the conventional one.

## Keywords

Metamaterials, Complementary Spiral Resonators (CSRs), Phase Shifters.

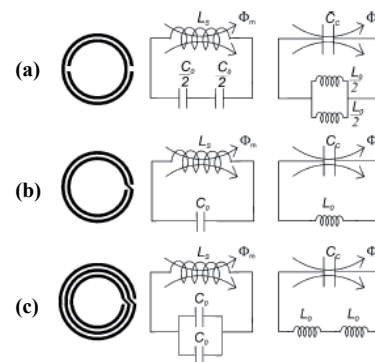
## 1. Introduction

Planar microwave components exhibit, generally, large dimensions. Several techniques have been presented in order to miniaturize these devices. An example could be the use of semi-lumped capacitors, inductors and resonators for the design of microwave filters [1]. In recent years, the use of metamaterial-based transmission lines, consisting on a host line loaded with reactive elements, is another alternative to achieve a high degree of miniaturization. This is due to their small electrical length. Moreover, these lines exhibit a controllable dispersion diagram which is of interest for the design of microwave devices with enhanced bandwidth or dual-band operation, based on dispersion engineering.

It is well known that there are two main approaches for the synthesis of metamaterial transmission lines: i) the CL-loaded approach, where a host line is loaded with series capacitances and shunt inductances [2-4], and ii) the resonant-type approach, where the loading elements are split ring resonators (SRRs) [5], or their complementary counterparts, that is, the complementary split ring resonators (CSRRs) [6].

In previous works developed by some of the authors, the resonant-type approach has been used not only to design miniaturized filters [7] and other microwave

components [8], but also to obtain devices with improved characteristics or novel functionalities, like enhanced bandwidth [9] and dual band components [10]. The great potential of this kind of lines for their application in microwave components has been clearly demonstrated with the presented examples. Further miniaturization can be obtained by means of particles derived from the SRR: the spiral resonator (SR) and the three turns spiral resonator (SR3) [11]. Topologies and their equivalent circuits are represented in Fig. 1 [12], where  $C_0$  is the edge capacitance between the two rings over the whole circumference, and  $L_s$  is the inductance of a single ring and average radius, as described in [12].



**Fig. 1.** SRR (a) and particles derived from the SRR: b) the SR and c) the SR3. The equivalent circuit models are depicted in the second column and the models for the complementary counterparts are in the third column. Extracted from [12].

From the equivalent circuits, it can be seen that there is a reduction of the resonance frequency with respect to the SRR. The capacitance value for a SRR is  $C_0/4$ , whereas for a SR is  $C_0$  and for a SR3 is  $2C_0$ . So, the resonance frequencies ratios are:

$$f_{OSRR} \approx 2f_{OSR} \approx 2\sqrt{2}f_{OSR3}. \quad (1)$$

It is obvious that we obtain a smaller particle for the same desired resonance frequency using these topologies. Comparing the sizes of SRR, SR and SR3 presenting the same resonant frequency we can see that the reduction factor is about 50% for the SR and 65% for the SR3 as

compared to the SRR (Fig. 2). These miniaturized particles have been used for the design of artificial magnetic meta-material media [13].

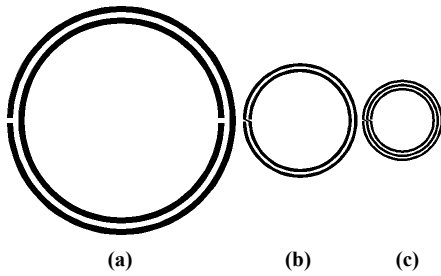


Fig. 2. Comparison between a SRR (a), a SR (b) and a SR3 (c) presenting the same resonance frequency. The reduction factors are approximately 50% and 65% with respect to the original SRR.

To synthesize artificial resonant-type transmission lines in microstrip technology, we should use the complementary counterparts of these particles. A typical unit cell based on a complementary spiral resonator (CSR) and its equivalent circuit model are depicted in Fig. 3. This circuit model is the same for the CSRR-based cells, but it is depicted here for completeness.  $L$  is the line inductance,  $C_g$  depends on the capacitive gap, the CSR etched on the ground plane is modeled by the  $L_c$ - $C_c$  resonant tank, and  $C$  represents the coupling between the line and the resonator (including the line capacitance and the fringing capacitance corresponding to the series gap) [14]. At low frequencies, the loading elements are dominant and wave propagation is backward (left-handed). At higher frequencies wave propagation is forward (right-handed), because the dominant elements are those that model the host line. These two transmission bands are usually separated by a gap, which can be collapsed by forcing the series and shunt resonance frequencies of the T-circuit model to be equal, obtaining a balanced cell [15]. Using this case it is possible to design zero-degree transmission lines.

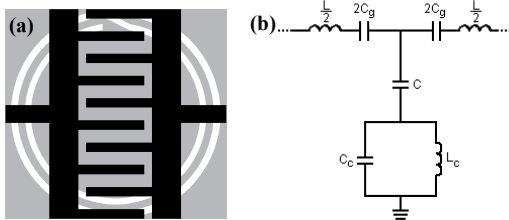


Fig. 3. Unit cell of the CSR-based artificial line (a) and equivalent T-circuit model (b). Top metal is depicted in black, whereas bottom metal is depicted in gray.

In Fig. 3(a), it can be seen that the series capacitance is implemented by means of an interdigital structure. This indicates that we need a higher value of  $C_g$  as compared with the CSRR-based implementation, due to the reduction of line inductance (the use of miniaturized resonators only makes sense if the length of the host line is also reduced), to preserve the required electrical characteristics. In this work, this structure is used for the design of compact power dividers with output lines exhibiting a  $90^\circ$  phase

difference, which will be called quadrature phase shifters from now on.

## 2. Design of Compact Quadrature Phase Shifters

The considered phase shifter consists on a Y-junction with a  $90^\circ$  admittance inverter, presenting a characteristic impedance of  $35.35 \Omega$  to preserve the input matching, and output lines that exhibit a phase difference of  $90^\circ$  at the frequency of interest. In the conventional device the output lines have an electrical length of  $+90^\circ$  and  $+180^\circ$  and a characteristic impedance of  $50 \Omega$  (Fig. 4a). In this paper, two variations of this topology are presented: i) output lines replaced with artificial cells, and ii) output lines and admittance inverter replaced by artificial cells. The design frequency for all these devices is  $1.55 \text{ GHz}$ .

### 2.1 Quadrature Phase Shifter with Meta-material Output Lines

In this case, only the  $50 \Omega$  output lines are replaced by a  $-90^\circ$  left-handed cell and a  $0^\circ$  balanced cell (setting the series and shunt resonance frequencies of the equivalent circuit model to be equal at the design frequency) [15], thus preserving the  $90^\circ$  phase balance provided by  $+90^\circ$  and  $+180^\circ$  output lines in the conventional device. This idea was implemented before by the authors, designing the device by means of CSRR-based cells for the same frequency, and obtaining an enhanced bandwidth phase balance response (Fig. 4b) [16].

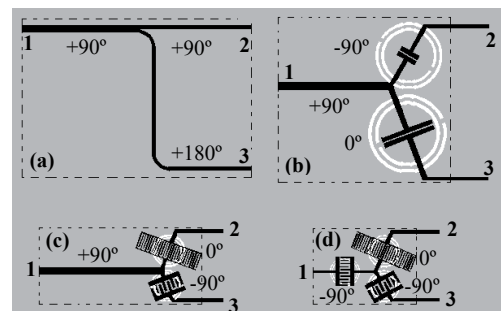


Fig. 4. Comparative layouts (drawn to scale) of the four quadrature phase shifters: conventional (a), CSRR-based (b) [16], device with two CSR-based cells (c), device with three CSR-based cells (d). Top metal is depicted in black, whereas bottom metal is depicted in gray. All devices have been implemented on the *Rogers RO3010* substrate with  $\epsilon_r = 10.2$  and thickness  $h = 635 \mu\text{m}$ . The active area is indicated by means of a dashed rectangle. The reduction factors, as compared with the conventional implementation, are 20%, 64% and 77%, respectively.

In order to design the CSR-based metamaterial transmission lines, we must set the desired phase  $\phi$  and characteristic impedance  $Z_B$  at the frequency of interest. These parameters are given by:

$$\cos \phi = 1 + \frac{Z_s(\omega)}{Z_p(\omega)}, \quad (2)$$

$$Z_B = \sqrt{Z_s(\omega)[Z_s(\omega) + 2Z_p(\omega)]} \quad (3)$$

where  $Z_s$  and  $Z_p$  are the series and shunt impedances of the T-circuit model. From these equations, and following the procedure described in [8] it is possible to design the desired artificial lines. The dimensions of the  $-90^\circ$  cell are: line length  $l=5.07$  mm, line width  $w=0.56$  mm, CSR external radius  $r_{\text{ext}}=2.44$  mm, spiral width  $c=0.22$  mm, spiral separation  $d=0.22$  mm and the interdigital capacitor is formed by 8 fingers separated 0.26 mm. For the  $0^\circ$  cell, dimensions are:  $l=6.68$  mm,  $w=0.56$  mm,  $r_{\text{ext}}=2.43$  mm,  $c=0.21$  mm,  $d=0.20$  mm and 28 fingers separated 0.16 mm forming the interdigital capacitor. The proposed phase shifter is shown in Fig. 4c, and the simulation and measurements of the power splitting and phase balance for the device are shown in Fig. 5. The shift between measurement and simulation is mostly attributed to a variation of the dielectric constant of the substrate and to fabrication related tolerances. It has been verified from measurement that the substrate dielectric constant is 15% higher than the nominal value, which explains in part the shift towards smaller frequencies in measurement. In this case, it has not been possible to enhance phase balance bandwidth. As has been pointed in Section 1, it is necessary a higher value of  $C_g$  with respect to CSRR-based cells to obtain the required characteristics. In this way, the gap capacitance value required to balance the  $0^\circ$  cell is much higher than the value required for the  $-90^\circ$  cell, and this makes difficult to achieve similar slopes in the phase responses of each cell (as it is required to enhance bandwidth), with the consequence of a higher derivative of the phase difference with the frequency.

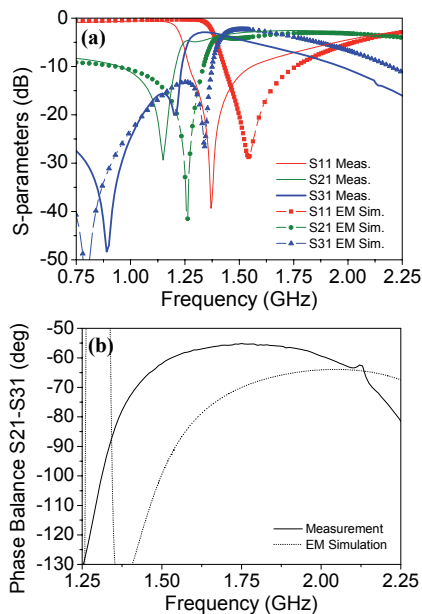


Fig. 5. Simulated and measured power splitting and matching (a) and phase balance (b) for the device of Fig. 4(c).

## 2.2 Quadrature Phase Shifter with Metamaterial Output Lines and Admittance Inverter

In [14], the admittance inverter was not replaced with a metamaterial-based one in order to enhance bandwidth. In the present case, we have seen that it is not possible to enhance bandwidth using CSR-based cells, so the  $35.35 \Omega$  admittance inverter could be also replaced with a  $-90^\circ$  left-handed line in order to achieve further miniaturization. Dimensions of this new cell are:  $l=9.55$  mm,  $w=0.37$  mm,  $r_{\text{ext}}=2.26$  mm,  $c=0.15$  mm,  $d=0.16$  mm and 10 fingers separated 0.28 mm forming the interdigital capacitor. This metamaterial-based admittance inverter presents a length of  $0.13\lambda$  (where  $\lambda$  is the guided wavelength at the design frequency). The CSR-based cell topology allows us to design even a shorter line (the  $-90^\circ$  and  $50 \Omega$  output line is  $0.07\lambda$ ), but there is the need of correctly connect the three cells to implement the device. The proposed phase shifter is shown in Fig. 4d, and the simulation and measurements of the power splitting and phase balance for the device are shown in Fig. 6. As in Fig 5, a frequency shift between measurement and simulation can be appreciated, and it is attributed to the same factors.

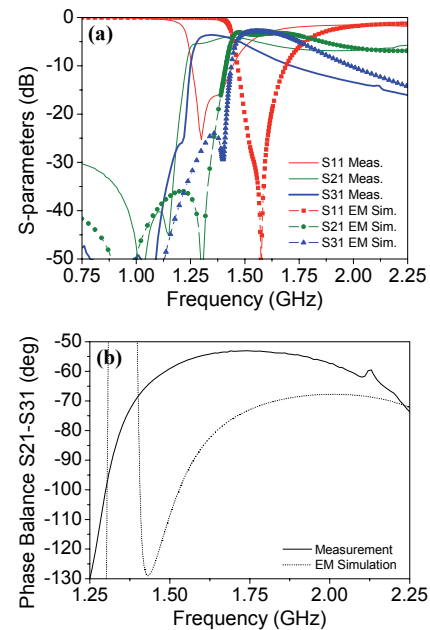


Fig. 6. Simulated and measured power splitting and matching (a) and phase balance (b) for the device of Fig. 4(d).

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